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NATIONAL AERONAUTICS AND SPACE ADMINISTRATION

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ANGULAR DISTRIBUTION OF THICK-TARGET BREMSSTRAHLUNG WHICH INCLUDES MULTIPLE ELECTRON SCATTERINGS*

By W. Wayne Scott Langley Research Center

SUMMARY

A theoretical analysis which includes multiple electron scattering as described by a random-walk procedure is presented for predicting the spectrum of bremsstrahlung produced at angles relative to a monoenergetic flux of electrons of normal incidence on thick targets. The assumption is made that the spectral and angular distribution of radiation leaving a thick target can be considered to be the sum of the contributions from a series of thin strips, one behind the other, bombarded by electrons of continuously decreasing energy. The following processes are considered in the analysis: (1) radiation of electrons in thin targets as predicted by the Bethe-Heitler theory; (2) electron penetration into the target which includes (a) multiple electron scattering as predicted by Goudsmit-Saunderson theory, (b) electron backscatter out of the target, (c) electron energy loss in the target, and (d) electron-electron bremsstrahlung; and (3) the absorption and buildup of photons in the target. Comparisons are made between the calculated results and experimental data for aluminum and iron thick targets. On the whole the agreement is reasonably good.

INTRODUCTION

Electrons that exist in the radiation belt (for example, ref. 1) surrounding the earth present a radiation hazard to man and equipment in space explorations. This hazard to manned space vehicles from electrons is primarily in the form of penetrating secondary radiation produced by the energy degradation of electrons in the space-vehicle wall. The radiation, designated as bremsstrahlung, results from interactions of the incoming electrons with the charged particles (nuclei or electrons) of which the vehicle wall is composed.

^{*}Some of the information presented herein was included in a thesis entitled "A Formula for Predicting the Angular Distribution of Thick Target Bremsstrahlung" submitted in partial fulfillment of the requirements for the degree of Master of Arts, The College of William and Mary in Virginia, Williamsburg, Virginia, 1965.

A vehicle wall could be treated as a thin target if, while traversing the wall, the incident electron has only one radiative collision, suffers no significant elastic deflection, and loses no appreciable energy by ionization. However, in practice, these conditions seldom exist. Generally a space-vehicle wall will be representative of a thick target; that is, the wall will be of such a thickness that the majority of the incident electrons will lose sufficient energy to be stopped. For this case, the description of the bremsstrahlung field behind the target is a difficult problem, complicated by multiple electron scattering, electron energy losses, photon absorption, and shower production.

Previous estimates of the bremsstrahlung spectra from thick targets for electrons with energies of the order of the rest-mass energy (0.511 MeV) have depended upon the theory developed by Kramers. (See ref. 2.) However, the validity of Kramers' theory is limited in that the theory estimates the photon energy distribution integrated over all directions of the emitted photons and the theory is nonrelativistic. Estimates have also been made by Wilson (ref. 3), the author of the present paper (ref. 4), and others but these results are also in the form of an average over the direction of photon emission and no attempt is made to account for multiple electron scattering within the target.

The analysis presented herein is intended to provide a basic formula for approximating, with a reasonable degree of accuracy, the thick-target bremsstrahlung spectrum. This approximating capability is important for shielding studies since experimental data are scarce and there is a need for theoretical data over a wide electron energy and material range.

The procedure for computing the bremsstrahlung spectra is programed in the FORTRAN (FORmula TRANslation) IV language for the IBM 7094 electronic data processing system at the Langley Research Center.

SYMBOLS

A atomic weight of target material

A₁,a₁,A₂,a₂ photon buildup coefficients

- B photon buildup factor
- c speed of light, centimeters per second
- E total electron energy, in units of m_0c^2

total energy of electron emergent from thin target i (i = 1, 2, ..., n), in $\mathbf{E_{i}}$ units of moc2 total electron energy after scattering, in units of moc2 \mathbf{E}^{\dagger} residual energy of scattering center after collision, in units of moc2 \mathbf{E}^{α} initial total electron energy, in units of moc2 E electron charge, electrostatic units е Planck constant, 6.6254×10^{-27} erg-seconds h mean ionization potential, in units of $m_{\alpha}c^2$ Ī indexing integers i, α, γ vector energy of emitted photon, in units of $m_{\alpha}c^2$ k electron rest mass, grams mo m_0c^2 electron rest-mass energy, 0.511 MeV atomic density, atoms per centimeter³ N Avogadro's number, atoms per gram-mole N_A number of atoms per centimeter per unit area, atoms per centimeter³ N_a number of thick-target subdivisions n \mathbf{P}_{ϵ} probability of electron being scattered at an angle ϵ P₁ Legendre polynomial electron momentum vector, in units of moc p

initial electron momentum vector, in units of $m_{o}c$

 p_{o}

momentum vector of electron after scattering, in units of moc p' electron spatial displacement vector, grams per centimeter² r classical electron radius, 2.81784×10^{-13} centimeter $\mathbf{r}_{\mathbf{o}}$ electron kinetic energy, in units of $m_{\Omega}c^2$ \mathbf{T} initial electron kinetic energy, in units of moc2 To path length traversed by electron t line-of-sight distance in target material between source point of photon and $\mathbf{t}_{\mathbf{x}}$ point at which the photon exits back surface of thick target, grams per centimeter² mean target thickness, grams per centimeter² Ŧ electron velocity after collision, centimeters per second v electron velocity before collision, centimeters per second vo W ratio of backscattered electrons to primary electrons X, Y, Zcoordinate axes of target atomic charge number \mathbf{Z} number of increments in the angle ϵ β δ number of increments in the angle ψ polar angle of electron, degrees ϵ polar angle of electron in thin target i, degrees $\epsilon_{\mathbf{i}}$ photon emission angle of k with respect to p_0 , degrees θ_{0} ξ first-approximation correction factor

 $\mu_{
m m}$ photon mass absorption coefficient, grams per centimeter² $\rho \qquad {
m density \ of \ target \ material, \ grams \ per \ centimeter^3}$ ${
m d} \sigma \qquad {
m differential \ bremsstrahlung \ cross \ section, \ centimeter^2 \ per \ atom-electron}$ ${
m d} \qquad {
m polar \ angle \ referred \ to \ k, \ degrees}$ ${
m polar \ angle \ of \ detector \ with \ respect \ to \ incident \ electron \ direction, \ degrees}$ ${
m d} \qquad {
m polar \ angle \ of \ electron \ in \ thin \ target \ \ i, \ degrees}$ ${
m d} \qquad {
m solid \ angle, \ steradians}$

THEORY OF THICK-TARGET ANALYSIS

For a monoenergetic, monodirectional beam of electrons incident on a thick target, a random-walk computer program for the analysis of thick-target bremsstrahlung has been generated. This analysis takes into account various aspects of electron penetration and diffusion: angular deflection, energy losses, spatial propagation, and the radiative process of scattering. The large number of interactions (running into the tens of thousands) which an electron may undergo in a thick target makes it necessary to resort to a sophisticated scheme in which many successive collisions are grouped into a single step of an artificial random walk. The scattering probabilities for the random walk are then obtained from pertinent analytical multiple electron scattering theories (e.g., ref. 5) governing angular deflections and energy losses.

The random-walk scheme must provide, for each step of the random walk, a rule for selecting an energy-loss increment E_i - E_{i+1} , a step length r_i - r_{i+1} , a change of electron direction from $\left(\epsilon_{\alpha}, \psi_{\gamma}\right)$ to $\left(\epsilon_{\alpha+1}, \psi_{\gamma+1}\right)$, and a spatial displacement \overline{r}_i - \overline{r}_{i+1} . A great variety of schemes are possible, which differ with regard to the input parameters and the necessary amount of computing time. The rules used for the random-walk sampling presented herein have been described in some detail by Berger in reference 5.

For this analysis a continuous slowing-down approximation is used to select a constant electron energy loss $\Delta E = E_i - E_{i+1}$; that is, the thick target is subdivided into a number of thin strips in each of which an electron energy loss ΔE occurs. For example, one may consider a target those thickness corresponds to the range of a

1-MeV electron (approximately $0.5~\rm g/cm^2$ of aluminum). The arbitrary selection can be made to subdivide the target into 20 thin targets each of which corresponds to an energy loss of $0.05~\rm MeV$.

The length t_i in each thin target is a function of the energy-loss increment according to the following relation

$$\left|t_{i} - t_{i+1}\right| = \int_{E_{i}}^{E_{i+1}} \frac{dE}{\frac{1}{\rho} \frac{dE}{dt}}$$
 (1)

where $\frac{dE}{dt}$ is the energy loss per centimeter of path length in the target. The mechanism for this energy loss is discussed in more detail in the section "Electron backscatter out of the target."

A simplifying assumption is made for the spatial displacement \overline{r}_i - \overline{r}_{i+1} . Essentially the spatial displacement parameter \overline{r} will be reduced from three dimensions to one dimension; for example, the spatial position of the electron is considered to be along the projected path of the initially incident electron at all times and no lateral deflection in position is to be considered at each scattering. This assumption is reasonable since the total path length of the electron within the target is itself relatively small in comparison with the distance between the target and detector position. Thus, only a change of direction from $\left(\epsilon_{\alpha}, \psi_{\gamma}\right)$ to $\left(\epsilon_{\alpha+1}, \psi_{\gamma+1}\right)$ is considered to influence the bremsstrahlung spectrum.

The present analysis differs from the usual random-walk method. The random-walk method consists of sampling many electron trajectories (called case histories), starting each electron with initial energy E_0 , and following it until it comes to rest. In the present analysis, the electrons are forced to assume predetermined or preset directions (different combinations of polar angles $\epsilon_{\alpha}, \psi_{\gamma}$). Along each of the electron trajectories the change in the polar angles, at each scattering, is chosen by some arbitrary (unweighted) technique. Having chosen the polar angles, the result is then multiplied by the appropriate scattering probability for this chosen direction. It is in this particular sense of scoring that the present analysis differs from the usual random-walk method. The appropriate probability for the electron being scattered at each set of polar angles will be determined by the use of the Goudsmit-Saunderson theory.

In summary of the previous discussion, it can be said that the electron is presumed to be normally incident on the first of a series of thin targets with energy \mathbf{E}_0 . The bremsstrahlung production in the first thin target is then calculated. The electron direction is then changed and the bremsstrahlung production is again determined for the given parameters. The changing of electron direction and the calculation of bremsstrahlung

production is continued until all the predetermined angles have been assumed. The electron is then considered to be entering into the second thin strip at a normal angle of incidence with an energy of $E_{\rm O}$ - ΔE . This procedure of changing the angles and calculating the bremsstrahlung production is again repeated. This sequence of events (random-walk steps) is continued until the electron has been brought to rest. The thick-target spectrum is then considered to be the sum of the radiation contributions from each thin strip.

In the next section the complex processes of electron penetration and radiation are discussed in more detail, after which a formula for approximating the bremsstrahlung spectrum is derived.

ELECTRON RADIATIVE AND SCATTERING MECHANISMS

Radiation in a Thin Target

In passing through the field of a nucleus (or atom) an electron with energy E is deflected. As a result of this deflection there exists a certain probability that a light quantum (photon) of energy k is emitted with the electron making a transition to another state with residual energy E', where

$$E = E' + k + E_{\alpha}$$
 (2)

This interaction is shown in figure 1. In the radiative collision, shown in figure 1, the initial momentum of the incident electron becomes shared among three bodies: the residual electron, the scattering center, and the emitted photon. Therefore, the photon can have any energy up to the energy of the incident electron.

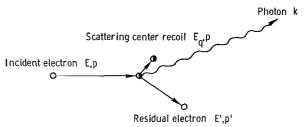


Figure I.- Radiative collision in a thin target.

The major part of the quantum-mechanical theory for predicting thin-target bremsstrahlung differential cross sections has been obtained by Bethe, Heitler (ref. 6), and others using the Born approximation. This approximation is valid provided

$$\frac{2\pi Ze^2}{hv_O} \ll 1 \tag{3}$$

and

$$\frac{2\pi Ze^2}{hv} << 1 \tag{4}$$

where v_0 and v represent the electron velocity before and after the collision, respectively. For light elements equations (3) and (4) are always satisfied if the primary and scattered electrons move with relativistic speeds. The Bethe-Heitler formula can be expressed as a differential with respect to two parameters, photon energy k and the solid angle Ω , as shown by the following equation. (See eq. (2BN) of ref. 7.)

$$d\sigma = \frac{Z^{2}r_{o}^{2}}{8\pi 137} \frac{p}{p_{o}} \frac{dk}{k} d\Omega \left\{ \frac{8 \sin^{2}\theta_{o} \left(2E_{o}^{2} + 1\right)}{p_{o}^{2}\Delta_{o}^{4}} - \frac{2\left(5E_{o}^{2} + 2EE_{o} + 3\right)}{p_{o}^{2}\Delta_{o}^{2}} - \frac{2\left(p_{o}^{2} - k^{2}\right)}{Q^{2}\Delta_{o}^{2}} + \frac{4E}{p_{o}^{2}\Delta_{o}} + \frac{4E}{p_{o}^{2}\Delta_{o}^{2}} + \frac{4E}{p_{o}^{2}\Delta_{o}^{2}} + \frac{4E}{p_{o}^{2}\Delta_{o}^{2}} + \frac{4E}{p_{o}^{2}\Delta_{o}^{2}} + \frac{2 - 2\left(7E_{o}^{2} - 3EE_{o} + E^{2}\right)}{p_{o}^{2}\Delta_{o}^{2}} + \frac{2k\left(E_{o}^{2} + EE_{o} - 1\right)}{p_{o}^{2}\Delta_{o}^{2}} - \frac{4\epsilon}{p\Delta_{o}} + \frac{\epsilon Q}{pQ} \left[\frac{4}{\Delta_{o}^{2}} - \frac{6k}{\Delta_{o}} - \frac{2k\left(p_{o}^{2} - k^{2}\right)}{Q^{2}\Delta_{o}}\right] \right\}$$

$$(5)$$

where

$$L = \log_{e} \left(\frac{EE_{O} - 1 + pp_{O}}{EE_{O} - 1 - pp_{O}} \right)$$

$$Q^2 = p_0^2 + k^2 - 2p_0 k \cos \theta_0$$

$$\Delta_{o} = E_{o} - p_{o} \cos \theta_{o}$$

$$\epsilon = \log_e \left(\frac{E + p}{E - p} \right)$$

and

$$\epsilon^{\mathbf{Q}} = \log_{\mathbf{Q}} \left(\frac{\mathbf{Q} + \mathbf{p}}{\mathbf{Q} - \mathbf{p}} \right)$$

Equation (5) represents the probability that a photon whose energy lies between the limits k and k+dk shall be emitted within a differential solid angle $d\Omega$, oriented at

some angle θ_0 with respect to the direction of motion of the incident electron when an electron of total energy E_0 collides with a thin target of atomic number Z. This collision geometry is shown in figure 2 for an electron approaching the origin along a positive Z-direction with momentum p_0 and colliding with a thin target which is considered to lie in the X-Y plane, perpendicular to the electron direction.

Various corrections must be made to the cross-section formula given by equation (5). These corrections may be classified according to three types:

- (1) Coulomb corrections
- (2) Screening corrections
- (3) Failure of the Born approximation at the high-frequency limit

Corrections (1) and (2) are significant in particular energy regions. This restriction on the energy region is unfortunate in that in the region of interest, approximately 0.1 to 2.0 MeV (intermediate energies), Coulomb corrections are not available in analytical form and empirical corrections cannot be determined in enough detail from the available data to cover the entire energy range. The screening corrections are not necessary in the intermediate energy region.

The problem of a high-frequency correction, or equivalently the problem of correcting the cross section for its larger error with increasing photon energy, is discussed in the section "The buildup and absorption of photons in the target."

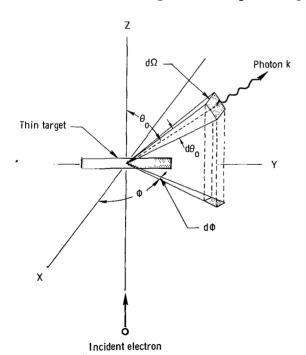


Figure 2.- Collision geometry of radiative process.

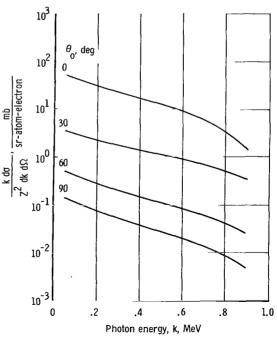


Figure 3.- Dependence of thin-target bremsstrahlung intensity spectrum on k and θ_0 . $T_0=1.0$ MeV.

In reference 4, the thin-target bremsstrahlung cross section was computed by using the Bethe-Heitler formula for a wide range of electron energies and for θ_0 equal to 0^0 , 30^0 , 60^0 , and 90^0 . One such spectrum from reference 4 is presented in figure 3 for a 1-MeV electron. For convenience the curve has been made independent of the atomic number Z, and the cross section is for a unit monoenergetic electron flux. It should be noted that the radiation intensity is peaked in the forward direction.

Electron Penetration Into a Thick Target

Multiple electron scattering. The phenomenon of an electron undergoing a large number of scatterings within a thick absorber is commonly referred to as multiple electron scattering. Each scattering results in an energy loss and a change of direction for the electron. As a consequence of the multiple electron scattering the angular distribution of the thick-target bremsstrahlung is altered. This alteration is recognized since the thin-target bremsstrahlung cross section (eq. (5)) is a function of the angle between the electron direction and the photon direction (detector direction) as shown in figure 4.

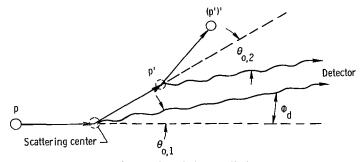


Figure 4.- Multiple electron scattering.

Therefore, if multiple electron scattering is to be included in the theoretical analysis, the array within each thin strip as illustrated in diagram A must be predicted.

The probability P_{ϵ} can be predicted by one of the many multiple scattering theories, some of which are based on the assumption that the scattering process is adequately described by ordinary diffusion. Goudsmit and Saunderson (ref. 8) have derived an expression of multiple Rutherford scattering by using a Legendre series expansion and assuming a continuous slowing down of the electron in the absorber. Their results are considered valid for all scattering angles and can be used with an appropriate single-scattering cross section, for example, a Mott cross section.

The evaluation of the Goudsmit-Saunderson theory is discussed in detail by Berger (ref. 5) who makes use of various procedures developed by Spencer (ref. 9) that facilitate the numerical evaluation of the angular multiple-scattering distribution function. The

i = 1	i = 2	7)	i = n - 1	i = n
E ₁	E ₂		E _{n-1}	E _n
€1	$^{\epsilon}2$	()	€ _{n-1}	εn
ψ_{1}	$\psi_{f 2}$) ($\psi_{\mathbf{n-1}}$	$\psi_{ m n}$
$\theta_{0,1}$	$ heta_{ ext{o,2}}$		θ _{0,n-1}	$\theta_{ m o,n}$
$P_{\epsilon,1}$	$P_{\epsilon,2}$) ($P_{\epsilon,n-1}$	$P_{\epsilon,n}$
$\left(\frac{\mathrm{d}\sigma}{\mathrm{d}\mathrm{k}\mathrm{d}\Omega}\right)_{1}$	$\left(\frac{\mathrm{d}\sigma}{\mathrm{d}\mathrm{k}\mathrm{d}\Omega}\right)_{2}$		$\left(\frac{\mathrm{d}\sigma}{\mathrm{d}k\ \mathrm{d}\Omega}\right)_{n-1}$	$\left(\frac{d\sigma}{dk\ d\Omega}\right)_n$
		Diagram A		

expression developed by Berger for the intensity of scattering per unit solid angle in the direction ϵ is given by

$$P_{\epsilon} = \sum_{l=0}^{\infty} \left(l + \frac{1}{2}\right) \exp\left[-\int_{0}^{t} G_{l}(t')dt'\right] P_{l}(\cos \epsilon)$$
 (6)

where

$$G_l(t') = 2\pi N \int_0^{\pi} \sigma(\theta, t') \left[1 - P_l(\cos \theta)\right] \sin \theta d\theta$$

and

N number of atoms per unit volume

t path length traversed by electron

 $\sigma(\theta,t')$ single-scattering cross section, whose dependence on the electron energy is expressed in the continuous slowing-down approximation, through the path length t

This expression (eq.(6)) is most applicable to a random-walk procedure where the target is subdivided into equal path lengths.

Results of an evaluation of equation (6) are presented in tables 1 and 2 for aluminum and iron and electron energies of 0.5 and 1.0 MeV. A typical plot of the multiple scattering is shown in figure 5 where the relative scattering probability is plotted as a function of the electron kinetic energy and angle of scattering.

Electron backscatter out of the target .-When a stream of electrons is directed against a solid target most of the electrons penetrate the target; however, some are emitted from the incident surface. A few of these returning electrons may be the products of collisions and are classed as secondary electrons. However, they are generally slow, most of them having an energy less than 50 eV. Most of the returning electrons, however, are members of the original beam, which have penetrated to a greater or lesser extent into the target, suffered elastic or inelastic collisions or both, and return to escape the front surface; thus, a reduction in the forward-going incident beam intensity takes place.

Several authors have made measurements to determine electron backscattering for electrons within the energy range of interest. One such plot using data from reference 10 is shown in figure 6 where the ratio of backscattered to primary electrons is plotted as a function of the target atomic number and the electron kinetic energy.

Electron energy loss in the target. The energy loss of electrons in a medium essentially occurs by two different mechanisms. The predominant mechanism of the energy degradation at low energies is due to the inelastic collisions

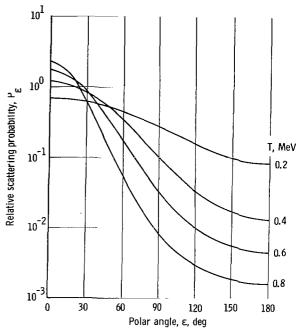


Figure 5.- Angular distribution of multiple scattered electrons in aluminum in which electron energy is reduced from $T_0 = 1.0$ MeV.

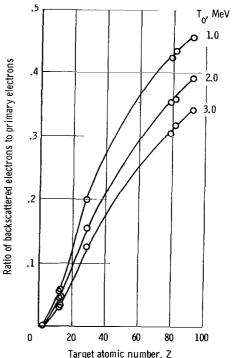


Figure 6.- Ratio of backscattered electrons to primary electrons as a function of target atomic number.

with the bound electrons of the medium, whereas at higher energies radiative collisions with the electric fields of the nuclei and the electrons become more important. It is shown in reference 11 that for lead the electron energy loss per unit path length of travel due to ionization is equal to that for radiative collisions at an approximate electron energy of 9 MeV, whereas for lower Z materials the equality occurs at much higher energies. Therefore, for the calculations presented herein it is assumed that the initial energy of the electron is sufficiently small so that radiative loss is negligible in comparison to ionization energy loss.

The energy loss per unit path length (called stopping power) due to ionizing collisions of the electron (ref. 12) is

$$-\frac{dE}{dt} = \frac{2\pi Ne^{4}Z}{m_{o}v^{2}} \left[log_{e} \frac{m_{o}v^{2}E}{2\overline{1}^{2}(1-\beta^{2})} - \left(2\sqrt{1-\beta^{2}}-1+\beta^{2}\right) log_{e} 2+1-\beta^{2} + \frac{1}{8}\left(1-\sqrt{1-\beta^{2}}\right)^{2} \right]$$
(7)

where

E total electron energy, in units of m_oc²

N atomic density, atoms/cm³

Z atomic charge number

e electron charge, esu

 \overline{I} mean ionization potential, in units of $m_0 c^2$

 $\beta = \frac{\mathbf{v}}{\mathbf{c}}$

m_o electron rest mass, g

v velocity of incident electron, cm/sec

c speed of light, cm/sec

As shown by equation (7), the energy loss per path increment is nonlinear with respect to the electron energy. Results of evaluating equation (7) for aluminum and iron are shown in tables 3 and 4, respectively.

Correction for electron-electron bremsstrahlung. When considering the passage of an electron through a medium, one must take into account the fact that the electron may also collide with the electrons of the atoms of which the medium is composed and produce bremsstrahlung. Calculations have been made to determine the exact electron-electron bremsstrahlung cross sections. (See ref. 6.) These calculations show that the final cross-section formula for electron-electron bremsstrahlung differs little (except for a factor of \mathbb{Z}^2) from the original electron-nucleus cross section for bremsstrahlung production. This conclusion is reasonable since large momentum transfers to a single electron are, though possible, rare and contribute little to the total bremsstrahlung cross section. The electron-electron bremsstrahlung contribution to the total bremsstrahlung cross section can thus be taken into account with a reasonable degree of accuracy by replacing the \mathbb{Z}^2 factor in the Bethe-Heitler formula (eq. (5)) by $\mathbb{Z}(\mathbb{Z}+1)$.

The buildup and absorption of photons in the target. When gamma rays traverse matter, they interact through separate "elementary" processes which have the effect of attenuating the photons either by outright absorption or by degradation in energy and deflection. These predominant elementary processes are the photoelectric effect, Compton scattering, and pair production.

In the photoelectric effect a photon disappears and an atomic electron leaves its atom, having absorbed the photon energy. This effect is predominant for low-energy gamma rays, especially in high Z materials.

In Compton scattering a photon is scattered inelastically and an atomic electron recoils out of an atom. This effect is predominant for 1- to 5-MeV gamma rays.

For pair production a gamma ray of more than 1 MeV disappears, and its energy transfers to an electron-position pair. This effect is predominant for high gamma ray energies, especially in high Z materials.

The interaction of gamma rays with matter results in an exponential attenuation of the gamma rays in the absorber. The number of photons traveling in the original incident direction after a distance of penetration t into the absorber is given by a function

of the form e $^{-\mu}{}_m{}^t$ where μ_m represents the mass attenuation coefficient (probability of a process per g/cm²).

The interaction processes experienced by photons give rise to a variety of secondary radiations, such as Compton scattered photons, electrons ejected in the photoelectric process, and pair-production electrons. The decay of the photoelectric and pair-production electrons results in secondary photons which influence the whole process of photon production. This effect of secondary photon generation in the absorber can be taken into account by the use of a buildup factor which is defined to be the ratio of the

total number of gamma rays at any one point to the number of primary gamma rays. An expression (found in ref. 13) for the buildup factors is given by

$$B(\mu_{m},t) = A_{1} \exp(-a_{1}\mu_{m}t) + A_{2} \exp(-a_{2}\mu_{m}t)$$
 (8)

where

 $\mu_{
m m}$ mass attenuation coefficient at source energy k

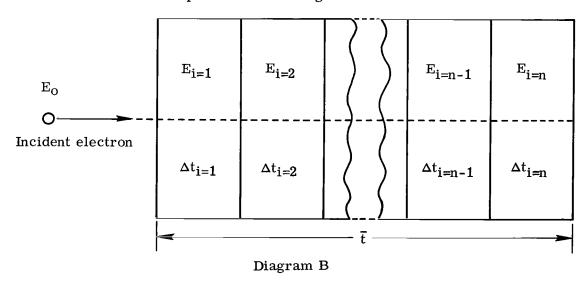
A₁,a₁,A₂,a₂ coefficients adjusted to fit experimentally determined data or theoretical data determined by Monte Carlo calculations

Tables 5 and 6 show the attenuation and buildup coefficients $\mu_{\rm m}$, A_1 , a_1 , A_2 , and a_2 for aluminum and iron, respectively.

DERIVATION OF THE THICK-TARGET EQUATION

It is now possible to approximate the angular distribution of bremsstrahlung behind a thick target by the combination of the complex processes discussed in the preceding sections.

Consider an electron of normal incidence on a thick target where the target has been subdivided into thin strips as shown in diagram B.



Within each thin target the electron will travel in some direction defined by the two polar angles ϵ and ψ . A schematic representation of a radiative scattering in any slab i is shown in figure 7.

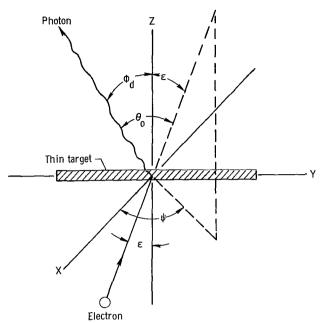


Figure 7.- General radiative scattering in thin target.

In this figure, ϵ is the angle between the electron velocity vector in the ith slab and the incident electron direction. Recall that the angle θ_0 is the angle between the electron velocity vector and the emitted photon. Note that only photons traveling at an angle ϕ_d with respect to the incident electron direction will reach the detector.

For a thick target which consists of many thin targets there will occur a scattering, typical of the scattering shown in figure 7, in each thin target. Figure 8 is representative of the present analysis of the multiple electron scattering that occurs in a thick target. Again as in figure 7, ϵ and ψ are the polar angles with ϵ representing the angle between the incident electron direction and

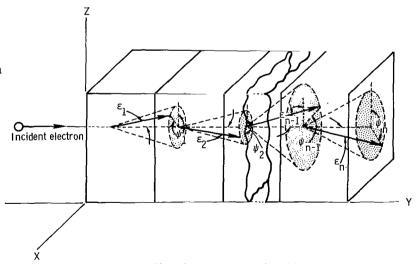


Figure 8.- Multiple electron scattering in thick target.

the electron velocity vector in the ith slab. Recall that the assumption is made that the lateral displacement of the electron within the target is very small compared with the distance between the target and detector and has negligible effect on the thick-target

spectrum. Thus the multiple scattering is considered to influence the spectrum only through changes in the electron direction with respect to the initially incident electron direction.

The path shown in figure 8 is certainly not unique. In other words, the path of the electron in the target is random; therefore, it is necessary to consider all directions of electron scattering in each slab relative to the initial electron direction. Within each slab all possible combinations of ϵ and ψ (fig. 7) are to be considered along with the representative probability of the electron having each particular combination of angles.

Now consider for each thin target a cylindrical differential element of volume dV having a normal unit area and length Δt (slab thickness) relative to the initial electron direction. The total probability for the emission of a photon of energy k in the direction θ_0 in each thin strip for a specified ϵ_{α} , ψ_{γ} , and ϕ_{d} is

$$\left[\frac{d\sigma}{dk\ d\Omega} \left(E_{i}, k, \theta_{o}\right) \Delta t\ N_{a}\right]_{i} \tag{9}$$

where N_a is the number of atoms/cm³. The photon energy release is dependent upon the angles ϵ , ψ , and ϕ_d , where these angles are related by the equation

$$\cos \theta_{o} = \cos \epsilon_{\alpha} \cos \phi_{d} + \sin \epsilon_{\alpha} \sin \phi_{d} \cos \psi_{\gamma}$$
 (10)

Expression (9) is an unweighted function with respect to the electron direction. The probability of the photon energy release must be correlated with the probability (weighted function) of the electron having the specific values of ϵ_{α} and ψ_{γ} . This scattering probability is expressed in equation (6) as a function of the particular thin target, electron energy, and angle ϵ . Hence,

$$P_{\epsilon} = \left[P_{\epsilon}(E_{i}, \epsilon_{\alpha})\right]_{i} \tag{11}$$

Thus for one electron direction of ϵ_{α} and ψ_{γ} the probability of the generation of a photon of energy k that will reach the detector at an angle ϕ_{d} is the product of the two probabilities

$$\left[\frac{d\sigma}{dk \ d\Omega} \left(\mathbf{E}_{i}, \mathbf{k}, \theta_{O} \right) \Delta t \ \mathbf{N}_{a} \mathbf{P}_{\epsilon} \left(\mathbf{E}_{i}, \epsilon_{\alpha} \right) \right]_{i} \tag{12}$$

For all angles of electron direction within each slab, that is, for ϵ varying from 0 to π and ψ varying from 0 to 2π , the total radiative probabilities in slab i are

$$\left(\frac{d\sigma}{dk\ d\Omega}\right)_{i} = \sum_{\alpha=0}^{\beta} \sum_{\gamma=0}^{\delta} \left[\frac{d\sigma}{dk\ d\Omega}\left(E_{i}, k, \theta_{o}\right) \Delta t\ N_{a} P_{\epsilon}\left(E_{i}, \epsilon_{\alpha}\right) \sin\frac{\alpha\pi}{\beta} \frac{\pi}{\beta} \frac{2\pi}{\delta}\right]_{i}$$
(13)

where

 $\alpha, \beta, \gamma, \delta$ integers

$$\epsilon_{\alpha} = \frac{\alpha \pi}{\beta}$$

$$\Delta \epsilon = \frac{\pi}{\beta}$$

$$\Delta \psi = \frac{2\pi}{\delta}$$

It is now necessary to sum these probabilities over the electron energy (or the corresponding thickness of the target necessary to bring the electron to rest). In theory it is possible to determine the differential path length of an electron within an absorber with the aid of equation (7), which is the relation expressing electron energy loss per unit path length. The differential path length is expressed as

$$dt = \frac{dE}{\frac{dE}{dt}}$$
 (14)

or

$$\Delta t = \frac{\Delta E}{\frac{dE}{dt}}$$
 (15)

where

$$\Delta E = \frac{E_0}{n}$$

Substituting equation (15) into equation (13) and summing over i slabs in terms of the electron energy give

$$\left(\frac{d\sigma}{dk\ d\Omega}\right)_{\text{thick target}} = \sum_{i=1}^{n} \sum_{\alpha=0}^{\beta} \sum_{\gamma=0}^{\delta} \left(\frac{d\sigma}{dk\ d\Omega}\right)_{\text{thin target}} \left(E_{i},k,\theta_{o}\right) \frac{N_{a}}{\frac{dE}{dt}} P_{\epsilon}\left(E_{i},\epsilon_{\alpha}\right) \sin \frac{\alpha\pi}{\beta} \frac{\pi}{\beta} \frac{2\pi}{\delta} \frac{E_{o}}{\delta}$$
(16)

Only electrons with energies greater than k can create photons of energy k; thus, a lower limit is placed on the energy summation. Rewriting and regrouping equation (16) and expressing the electron energy in terms of the total electron energy give

$$\left(\frac{d\sigma}{dk\ d\Omega}\right)_{thick\ target} = N_a \int_{k+m_0c^2}^{E_0} \frac{dE}{dt} \int_0^{2\pi} \int_0^{\pi} \left(\frac{d\sigma}{dk\ d\Omega}\right)_{thin\ target} P_{\epsilon} \sin\epsilon\ d\epsilon\ d\psi$$
(17)

The additional processes of photon absorption and buildup, electron-electron bremsstrahlung, and backscattering as previously discussed can now be included in equation (17) as follows:

$$\left(\frac{d\sigma}{dk\ d\Omega}\right)_{thick\ target} = N_{a}Z(Z+1)(1-W)\int_{k+m_{O}c^{2}}^{E_{O}} \left[\frac{Be^{-\mu}m^{t}x/\cos\phi_{d}}{dt} dE \int_{0}^{2\pi} \int_{0}^{\pi} \left(\frac{1}{Z^{2}} \frac{d\sigma}{dk\ d\Omega}\right)_{thin\ target} P_{\epsilon} \sin\epsilon\ d\epsilon\ d\psi\right]$$
(18)

where

 $e^{-\mu_{m}t_{x}/\cos\,\phi_{d}}$ photon absorption in target

B photon buildup

Z(Z + 1) approximate correction for electron-electron bremmstrahlung

1 - W correction for electron backscattering out of target

Intensity is now defined as the photon energy $\,k\,\,$ multiplied by the number of photons $\left(\frac{d\sigma}{dk\;d\Omega}\right)_{\mbox{thick target}} \mbox{ with energy }\,k. \mbox{ Thus, expressing equation (18) in terms of intensity and replacing }\,N_a\mbox{ by }\,N_A\rho/A\mbox{ give}$

$$\left(k \frac{d\sigma}{dk \ d\Omega}\right)_{thick \ target} = \frac{N_A}{A} \ Z(Z+1)(1-W) \int_{k+1}^{E_0} \left[\frac{Be^{-\mu} m^t x / \cos \phi_d}{\frac{1}{\rho} \frac{dE}{dt}} \right] dE \int_0^{2\pi} \int_0^{\pi} \left(\frac{k}{Z^2} \frac{d\sigma}{dk \ d\Omega}\right)_{thin \ target} P_{\epsilon} \sin \epsilon \ d\epsilon \ d\psi$$
(19)

where the integration

$$\int_0^{2\pi} \int_0^{\pi} \mathbf{P}_{\epsilon} \sin \epsilon \, d\epsilon \, d\psi \tag{20}$$

is normalized to one in each slab. Equation (19) now represents an expression for approximating the angular distribution of bremsstrahlung behind a thick target.

RESULTS AND DISCUSSION

Theoretical Results and Comparison With Experimental Data

Because there exists a scarcity of experimental thick-target data, a complete comparison between theory and experiment over a wide range of electron energies and materials cannot be made. However, some experimental data for both thick and thin aluminum and iron targets have been obtained by the LTV Research Center (refs. 14 and 15) and are used herein for comparison with theoretical calculations.

The comparisons of the theoretically predicted results (eq. (19)) with the experimental data for aluminum and iron thick targets and electron kinetic energies of 0.5 and 1.0 MeV are shown in tables 7 and 8 and figures 9 and 10. Each table is

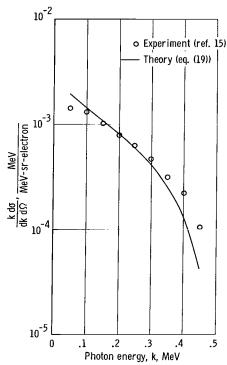


Figure 9.- Thick-target bremsstrahlung production in aluminum. $T_0 = 0.5 \text{ MeV}$; detector angle, 0^0 .

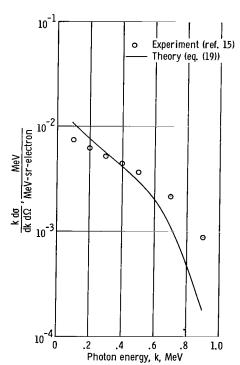


Figure 10.- Thick-target bremsstrahlung production in iron. $T_0=1.0~{\rm MeV};$ detector angle, $0^{\rm O}.$

representative of the thick-target bremsstrahlung production for a specific material, electron kinetic energy, and detector angle.

The values presented in tables 7(a) and 8(b) for $\theta_d = 0^0$ are plotted in figures 9 and 10 to show the general trend of comparison. Here the bremsstrahlung intensity is a function of the photon energy, detector angle, electron kinetic energy, and material. The theoretical results (obtained from evaluating eq. (19)) compare favorably with the experimental data over most of the photon energy range. The discrepancy that exists between the theoretical and experimental data is expected, inasmuch as the Born approximation technique is used in the theoretical thick-target model. The reason for this discrepancy is realized by comparing experimental thin-target data with the Bethe-Heitler theory. Figures 11 and 12 show this comparison for aluminum thin targets, detector angles of 150 and 30°, and incident electron energies of 0.5 and 1.0 MeV, respectively. It is seen from figures 11 and 12 that the Bethe-Heitler theory, in general, overestimates the intensity at the low photon energies and, as was previously anticipated, underestimates the spectrum in the high frequency region (i.e., upper photon energy range). Because the thick-target spectra are obtained by summing up the spectra for a series of thin targets, the discrepancy between the theory and experiment for the thick target is obvious and expected. Thus, the theoretical thick-target results are expected to overestimate the spectrum at the low photon energies and underestimate at the high frequency region.

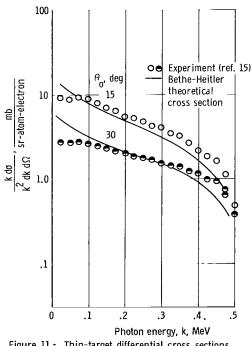


Figure 11.- Thin-target differential cross sections for 0.5-MeV bremsstrahlung at photon energies k and $\theta_0 = 15^{\circ}$ and 30° . Z = 13.

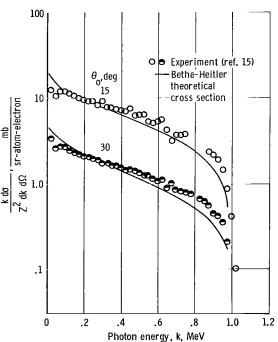


Figure 12.- Thin-target differential cross sections for 1.0-MeV bremsstrahlung at photon energies k and $\theta_0 = 15^{\circ}$ and 30° . Z = 13.

It is important to try to estimate the degree of improvement of the theory, as presented herein, over the usual simplified approach (straight through theory) of assuming that the electron suffers no multiple scattering. The equation describing straight through theory is

$$\left(k \frac{d\sigma}{dk \ d\Omega}\right)_{\text{thick target}} = \frac{N_A Z^2}{A} \int_{k+1}^{E_O} \left(\frac{k}{Z^2} \frac{d\sigma}{dk \ d\Omega}\right)_{\text{thin target}} \frac{1}{\frac{1}{\rho} \frac{dE}{dt}} dE$$
 (21)

One result of evaluating equation (21) for a 0.5-MeV electron incident on aluminum with a detector angle of 30° is shown in figure 13 along with the experimental data and results as predicted by equation (19). From figure 13, it is obvious that the inclusion of multiple electron scattering greatly improves the method for approximating the angular distribution of thick-target bremsstrahlung.

Numerical Correction to Thick-Target Bremsstrahlung Spectrum

The use of the Bethe-Heitler thin-target cross section in equation (19) introduces an unavoidable error in the thick-target spectrum. The difficulty, as previously stated, lies in the fact that the Bethe-Heitler theory does not predict a result in accordance with experiment. This discrepancy was previously shown in figures 11 and 12.

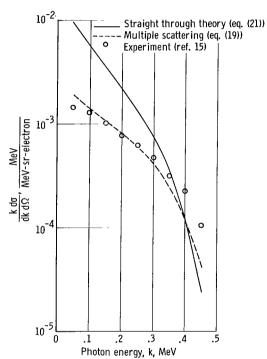


Figure 13.- Comparison of straight through theory with multiple scattering theory and experiment. Aluminum thick target; $T_0 = 0.5$ MeV; detector angle, 30^0 .

The present deficiency in the theoretical prediction of the thin-target cross section can be attributed almost entirely to the use of plane waves for the electron wave function in the matrix element for the radiative collisions as prescribed by the Born approximation. To improve the theoretical estimates, the Born approximation should be replaced with a formulation which uses electron-Coulomb wave functions. C. D. Zerby of Union Carbide Research Institute is presently developing for the NASA under Contract No. NASw-1235 the mathematical formulation of the electron bremsstrahlung cross section for unpolarized incident particles by using Coulomb wave functions. The difficulty with the

improved method, and the reason it has not been used extensively in the past, is that it does not yield a simple analytic formula but requires extensive numerical procedures to obtain results. When Zerby's calculations are available it is presumed that the results can replace the Bethe-Heitler analytic formula in the existing computer program.

Since no exact analytic expression exists for the thin-target cross section, the next logical approach is to correct for the discrepancy in the Bethe-Heitler relation with a semiempirical or empirical correction. Since in the energy region of the electron rest-mass energy (0.511 MeV) Coulomb corrections (ref. 7) to the Bethe-Heitler expression are not available in analytical form, a correction must be approximated from the limited experimental results available. This correction is made by considering the two following important assumptions:

- (a) The major contributions to the region of the intensity spectrum where the largest discrepancy exists (upper region in photon energy) result from electrons with energies near the incident electron energy that is, electrons that have just entered the incident surface.
- (b) The multiple scattering effects have not appreciably modified the electron distribution near the front face of the target.

As a result of making these two assumptions it is possible to use existing thintarget experimental data to correct the thick-target spectrum for some specific cases. In more general terms the thick-target spectrum (obtained from eq. (19)) is corrected for its discrepancy with experimental results by multiplying by a correction factor defined as $\xi(k)$. This factor is a function of the photon energy k and atomic number of the target material and represents the number by which the Bethe-Heitler thin-target cross section must be multiplied so that it agrees with experimental data.

Since a first-approximation correction factor has been defined, equation (19) can be written in the following way

$$\left(k \frac{d\sigma}{dk \ d\Omega}\right)_{\text{thick target}} = \frac{N_{A}}{A} Z(Z+1)(1-W) \int_{k+1}^{E_{O}} \left[\xi \frac{Be^{-\mu_{m}t_{x}/\cos\phi_{d}}}{\frac{1}{\rho} \frac{dE}{dt}} \int_{0}^{2\pi} \int_{0}^{\pi} \left(\frac{k}{Z^{2}} \frac{d\sigma}{dk \ d\Omega}\right)_{\text{thin target}} P_{\epsilon} \sin\epsilon \ d\epsilon \ d\psi\right] dE$$
(22)

As an illustrative example, equation (22) is used to determine the bremsstrahlung spectrum for a 0.5-MeV electron incident upon an aluminum thick target with a detector angle of 15° . Because of assumption (a) a thin-target spectrum with an incident electron kinetic energy of 0.5 MeV is chosen and because of assumption (b) the angle of observation $\theta_{\rm O}$ of the thin-target spectrum is chosen to correspond to the thick-target

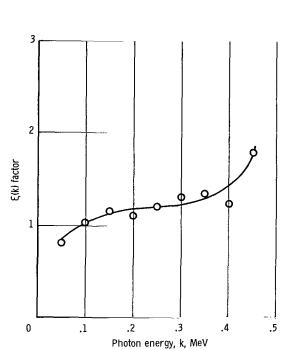


Figure 14.- A plot of $\xi(k)$ factor for 0.5-MeV electron. Aluminum target; detector angle, 150.

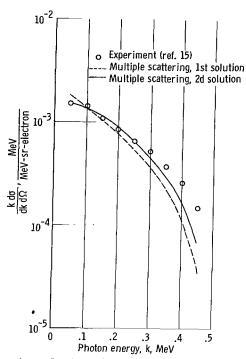


Figure 15.- Comparison of corrected multiple scattering theory (eq. (22)) with multiple scattering theory (eq. (19)) and experiment. Aluminum thick target; $T_0 = 0.5 \text{ MeV}$; detector angle, 15^0 .

detector angle ϕ_d , that is, $\phi_d = \theta_o = 15^o$. A thin-target spectrum of these angles was previously presented in figure 11 and the plot of the $\xi(k)$ factor for this spectrum is shown in figure 14. The results of this example are presented in figure 15 and it must be assumed that similar corrections can be made to all thick-target spectra provided the thin-target data exist for the corresponding electron kinetic energy and observation angle.

CONCLUDING REMARKS

The complication of multiple electron scattering within a thick absorber makes a rigorous analytical solution difficult for the prediction of the angular distribution of bremsstrahlung from completely stopped electrons. Therefore, an approximating formula has been presented for predicting the thick-target spectrum which is differential both in photon energy and angle of emission. This approximation is derived from the summation of the contribution from successive thin strips into which the absorber is divided.

The use of the thin-target Born approximation cross section for deriving the thick-target expression introduces an error that is presently unavoidable.

The comparisons between the results obtained from the theory derived herein and experimental data are favorable; thus, it can be concluded that the approximating formula for the angular distribution of electron bremsstrahlung in thick targets is valid and is an improvement over the usual straight through theory.

Langley Research Center,

National Aeronautics and Space Administration, Langley Station, Hampton, Va., December 20, 1966, 124-09-01-14-23.

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TABLE 1

ANGULAR DISTRIBUTION OF MULTIPLE SCATTERED

ELECTRONS IN ALUMINUM

(a) Electron energy reduced from $T_O = 0.5 \text{ MeV}$

ε,	P_{ϵ} for T, MeV, of -									
deg	0.45	0.40	0.35	0.30	0.25	0.20	0.15	0.10	0.05	
0	2.0060	1.6200	1.3500	1.0800	0.8200	0.6290	0.4520	0.3100	0.1987	
15	1.5810	1.3500	1.1700	.9580	.7760	.5921	.4352	.3001	.1802	
30	.8200	.7880	.7500	.6750	.5984	.4993	.3634	.2857	.1920	
45	.3186	.3510	.3850	.3960	.3973	.3703	.3160	.2582	.1894	
60	.1120	.1390	.1700	.2020	.2330	.2501	.2271	.2233	.1802	
75	.0420	.0540	.0745	.0980	.1276	.1590	.1783	.1860	.1740	
90	.0189	.0240	.0340	.0450	.0683	.0960	.1280	.1551	.1561	
105	.0100	.0120	.0180	.0250	.0382	.0553	.0890	.1242	.1506	
120	.0059	.0080	.0100	.0150	.0233	.0372	.0627	.1007	.1442	
135	.0046	.0054	.0075	.0100	.0152	.0251	.0448	.0830	.1381	
150	.0036	.0045	.0059	.0078	.0110	.0180	.0330	.0710	.1383	
165	.0031	.003È	.0050	.0067	.0097	.0155	.0290	.0656	.1359	
180	.0030	.0037	.0049	.0064	.0092	.0148	.0279	.0628	.1350	

(b) Electron energy reduced from $T_O = 1.0 \text{ MeV}$

ϵ ,	P_{ϵ} for T, MeV, of -								
deg	0.9	0.8	0.7	0.6	0.5	0.4	0.3	0.2	0.1
0	2.4786	2.2069	1.9412	1.6831	1.4288	1.1801	0.9220	0.6613	0.4119
15	1.7000	1.6318	1.5361	1.4105	1.2564	1.0771	.8737	.6433	.4087
30	.6276	.7210	.8004	.8542	.8704	.8382	.7451	.5909	.3986
45	.1729	.2352	.3133	.4035	.4927	.5572	.5735	.5158	.3827
60	.0497	.0735	.1108	.1661	.2422	.3310	.4090	.4286	.3624
75	.0179	.0267	.0418	.0679	.1129	.1826	.2717	.3426	.3395
90	.0082	.0120	.0186	.0307	.0537	.0983	.1736	.2657	.3154
105	.0046	.0066	.0099	.0161	.0283	.0547	.1098	.2026	.2926
120	.0030	.0042	.0062	.0098	.0169	.0330	.0713	.1545	.2716
135	.0022	.0030	.0044	.0069	.0115	.0220	.0491	.1202	.2539
150	.0018	.0025	.0036	.0054	.0089	.0165	.0368	.0980	.2405
165	.0016	.0022	.0031	.0047	.0076	.0140	.0308	.0853	.2323
180	.0015	.0021	.0030	.0045	.0073	.0133	.0290	.0817	.2297

TABLE 2

ANGULAR DISTRIBUTION OF MULTIPLE SCATTERED

ELECTRONS IN IRON

(a) Electron energy reduced from $T_0 = 0.5 \text{ MeV}$

ϵ ,				P_{ϵ} fo	r T, Me	V, of -			
deg	0.45	0.40	0.35	0.30	0.25	0.20	0.15	0.10	0.05
0	1.2476	1.1145	0.9866	0.8619	0.7264	0.5953	0.4741	0.3724	0.3221
15	1.1301	1.0324	.9298	.8177	.7029	.5818	.4678	.3704	.3214
30	.8453	.8153	.7696	.7127	.6326	.5428	.4495	.3647	.3214
45	.5379	.5644	.5733	.5635	.5377	.4854	.4218	.3564	.3208
60	.3051	.3488	.3884	.4182	.4299	.4170	.3865	.3450	.3202
75	.1618	.2021	.2469	.2917	.3280	.3474	.3480	.3316	.3189
90	.0854	.1143	.1518	.1961	.2425	.2820	.3089	.3176	.3183
105	.0474	.0665	.0935	.1304	.1769	.2381	.2724	.3042	.3176
120	.0289	.0411	.0599	.0884	.1294	.1813	.2408	.2915	.3164
135	.0197	.0279	.0413	.0629	.0978	.1483	.2150	.2807	.3157
150	.0150	.0211	.0313	.0485	.0779	.1257	.1961	.2724	.3151
165	.0128	.0179	.0264	.0411	.0673	.1129	.1847	.2673	.3151
180	.0121	.0169	.0249	.0388	.0638	.1086	.1809	.2660	.3144

(b) Electron energy reduced from $T_O = 1.0 \text{ MeV}$

ϵ ,	P_{ϵ} for T, MeV, of -									
deg	0.9	0.8	0.7	0.6	0.5	0.4	0.3	0.2	0.1	
0	1.6045	1.4244	1.2452	1.0710	0.8953	0.7227	0.5563	0.4092	0.3263	
15	1.3618	1.2505	1.1275	.9917	.8519	.6992	.5451	.4061	.3256	
30	.8573	.7928	.8468	.8032	.7271	.6287	.5141	.3965	.3250	
45	.4286	.4886	.5388	.5702	.5697	.5370	.4669	.3806	.3237	
60	.1904	.2451	.3061	.3649	.4113	.4301	.4104	.3616	.3224	
75	.0827	.1167	.1625	.2186	.2794	.3296	.3508	.3393	.3205	
90	.0390	.0571	.0855	.1274	.1828	.2444	.2937	.3158	.3180	
105	.0207	.0309	.0475	.0753	.1188	.1786	.2434	.2936	.3160	
120	.0127	.0187	.0290	.0471	.0786	.1310	.2011	.2726	.3141	
135	.0089	.0129	.0197	.0321	.0553	.0987	.1695	.2554	.3129	
150	.0069	.0100	.0150	.0243	.0424	.0787	.1471	.2427	.3116	
165	.0069	.0086	.0128	.0205	.0358	.0681	.1341	.2345	.3110	
180	.0058	.0082	.0121	.0194	.0338	.0646	.1297	.2319	.3103	

TABLE 3

STOPPING POWER OF ALUMINUM

[Atomic number Z, 13.00; atomic weight A, 26.9815]

TABLE 4

STOPPING POWER OF IRON

[Atomic number Z, 26.00; atomic weight A, 55.847]

Electron kinetic	Stopping power,	Electron kinetic	Stopping power,
energy, T,	$\underline{\text{MeV} - \text{cm}^2}$	energy, T,	$\underline{\text{MeV} - \text{cm}^2}$
MeV	g	MeV	g
0.01	$0.1688\text{E}\times10^2$	0.01	$0.1452\mathrm{E}\times10^{\textstyle 2}$
.02	$1004E \times 10^{2}$.02	$.8789\mathrm{E}\times10$
.03	$.7425E \times 10$.03	$.6546\mathrm{E}\times10$
.04	.6015E \times 10	.04	$.5328\mathrm{E}\times10$
.05	$.5127 ext{E} imes 10$.05	$.4556 ext{E} imes10$
.06	.4515E × 10	.06	$.4022E \times 10$
.07	$.4065E \times 10$.07	$.3629 ext{E} imes 10$
.08	$.3721E \times 10$.08	$.3327 ext{E} imes 10$
.09	.3450E \times 10	.09	$.3089 ext{E} imes10$
.10	.3229E imes 10	.10	$.2895 extbf{E} imes10$
.20	.2211E × 10	.20	$.1996 ext{E} imes 10$
.30	$.1873E \times 10$.30	$.1697\mathrm{E}\times10$
.40	$.1714E \times 10$.40	$.1557\text{E}\times10$
.50	$.1627 ext{E} imes 10$.50	$.1481\mathrm{E}\times10$
.60	.1576E × 10	.60	$.1437\mathrm{E}\times10$
.70	$.1545E \times 10$.70	$.1410 \text{E} \times 10$
.80	.1526E × 10	.80	$.1395 ext{E} imes 10$
.90	.1515E × 10	.90	$\textbf{.1386E} \times \textbf{10}$
1.00	.1509E × 10	1.00	$.1381E \times 10$
2.00	.1538E × 10	2.00	$.1416 ext{E} imes10$
3.00	.1594E \times 10	3.00	.1471E $ imes$ 10
4.00	$.1643E \times 10$	4.00	$.1519E \times 10$
5.00	.1685E $ imes$ 10	5.00	$.1559 \text{E} \times 10$
6.00	.1721E $ imes$ 10	6.00	.1594E $ imes$ 10
7.00	.1752E $ imes$ 10	7.00	$\textbf{.}1625\text{E}\times10$
8.00	.1779E \times 10	8.00	.1651E $ imes$ 10
9.00	.1804E × 10	9.00	$.1675 \text{E} \times 10$
10.00	.1826E × 10	10.00	.1697E $ imes$ 10

TABLE 5
ATTENUATION AND BUILDUP COEFFICIENTS FOR ALUMINUM

k, MeV	μ _m , cm ² /g	A ₁	a ₁	A ₂	a ₂
$10.00E \times 10^{-2}$	8.00E	$1.69E \times 10^{-1}$	$-1.10E \times 10^{-1}$	-7.00E	$4.40E \times 10^{-2}$
$2.00E \times 10^{-1}$	8.00E	$1.22E \times 10^{-1}$	$-1.10E \times 10^{-1}$	-7.00E	$4.40E \times 10^{-2}$
$3.00E \times 10^{-1}$	8.00E	$1.04E \times 10^{-1}$	$-1.10E \times 10^{-1}$	-7.00E	4.40E × 10 ⁻²
$4.00E \times 10^{-1}$	8.00E	$9.30E \times 10^{-2}$	$-1.10E \times 10^{-1}$	-7.00E	$4.40E \times 10^{-2}$
$5.00E \times 10^{-1}$	8.00E	$8.40E \times 10^{-2}$	-1.10E × 10 ⁻¹	-7.00E	$4.40E \times 10^{-2}$
$6.00E \times 10^{-1}$	8.00E	$7.80E \times 10^{-2}$	$-1.10E \times 10^{-1}$	-7.00E	$4.40E \times 10^{-2}$
$7.00E \times 10^{-1}$	8.00E	$7.30E \times 10^{-2}$	$-1.10E \times 10^{-1}$	-7.00E	$4.40E \times 10^{-2}$
$8.00E \times 10^{-1}$	8.00E	$6.80E \times 10^{-2}$	$-1.10E \times 10^{-1}$	-7.00E	$4.40E \times 10^{-2}$
$9.00E \times 10^{-1}$	8.00E	$6.50E \times 10^{-2}$	$-1.10E \times 10^{-1}$	-7.00E	$4.40E \times 10^{-2}$
1.00E	8.00E	$6.10E \times 10^{-2}$	-1.10E × 10 ⁻¹	-7.00E	$4.40E \times 10^{-2}$
1.50E	6.75E	$5.00E \times 10^{-2}$	$-9.40E \times 10^{-2}$	-5.75E	$6.90E \times 10^{-2}$
2.00E	5.50E	$4.30E \times 10^{-2}$	$-8.20E \times 10^{-2}$	-4.50E	$9.30E \times 10^{-2}$
3.00E	4.50E	$3.50E \times 10^{-2}$	$-7.40E \times 10^{-2}$	-3.50E	$1.16E \times 10^{-1}$
4.00E	3.80E	$3.10E \times 10^{-2}$	$-6.60E \times 10^{-2}$	-2.80E	$1.30E \times 10^{-1}$
5.00E	3.40E	$2.80E \times 10^{-2}$	$-6.50E \times 10^{-2}$	-2.40E	$1.41E \times 10^{-1}$
6.00E	3.10E	$2.60 \mathrm{E} imes 10^{-2}$	$-6.40E \times 10^{-2}$	-2.10E	$1.52E \times 10^{-1}$
7.00E	2.70E	$2.50E \times 10^{-2}$	$-6.30E \times 10^{-2}$	-1.70E	$1.50E \times 10^{-1}$
8.00E	2.30E	$2.40\mathrm{E}\times10^{-2}$	$-6.20E \times 10^{-2}$	-1.30E	$1.50E \times 10^{-1}$
9.00E	2.27E	$2.30E \times 10^{-2}$	$-6.10E \times 10^{-2}$	-1.27E	$1.39E \times 10^{-1}$
1.00E × 10	2.25E	$2.30\mathrm{E}\times10^{-2}$	$-6.00E \times 10^{-2}$	-1.25E	$1.28E \times 10^{-1}$

 $\mbox{ TABLE 6}$ ATTENUATION AND BUILDUP COEFFICIENTS FOR IRON

k, MeV	$\frac{\mu_{\rm m}}{{ m cm}^2/{ m g}}$	A ₁	a ₁	A ₂	a ₂
$10.00E \times 10^{-2}$	$3.44E \times 10^{-1}$	$1.17\mathrm{E} imes 10$	$-9.90E \times 10^{-2}$	-1.07E × 10	0
$2.00E \times 10^{-1}$	$1.38E \times 10^{-1}$	$1.11\mathrm{E} imes 10$	$-9.80E \times 10^{-2}$	-1.01E × 10	$4.00E \times 10^{-3}$
$3.00E \times 10^{-1}$	$1.06E \times 10^{-1}$	1.07E × 10	$-9.70E \times 10^{-2}$	-9.70E	$7.00E \times 10^{-3}$
$4.00E \times 10^{-1}$	$9.19E \times 10^{-2}$	1.03E × 10	$-9.60E \times 10^{-2}$	-9.30E	$10.00E \times 10^{-3}$
$5.00E \times 10^{-1}$	$8.28E \times 10^{-2}$	$1.00E \times 10$	$-9.50E \times 10^{-2}$	-9.00E	$1.25E \times 10^{-2}$
$6.00E \times 10^{-1}$	$7.62E \times 10^{-2}$	9.70E	$-9.40E \times 10^{-2}$	-8.70E	$1.75E \times 10^{-2}$
$7.00E \times 10^{-1}$	$7.00E \times 10^{-2}$	9.40E	$-9.20E \times 10^{-2}$	-8.40E	$1.90E \times 10^{-2}$
$8.00E \times 10^{-1}$	$6.64E \times 10^{-2}$	9.10E	$-9.00E \times 10^{-2}$	-8.10E	$2.25E \times 10^{-2}$
$9.00E \times 10^{-1}$	$6.20E \times 10^{-2}$	8.80E	$-8.95E \times 10^{-2}$	-7.80E	$2.60E \times 10^{-2}$
1.00E	$5.95E \times 10^{-2}$	8.60E	$-8.80E \times 10^{-2}$	-7.60E	$2.80E \times 10^{-2}$
1.50E	$4.60E \times 10^{-2}$	7.50E	$-8.00E \times 10^{-2}$	-6.50E	$4.00E \times 10^{-2}$
2.00E	$4.20E \times 10^{-2}$	6.60E	$-7.30E \times 10^{-2}$	-5.60E	$4.90E \times 10^{-2}$
3.00E	$3.60E \times 10^{-2}$	5.00E	$-7.20E \times 10^{-2}$	-4.00E	$6.20E \times 10^{-2}$
4.00E	$3.30E \times 10^{-2}$	4.00E	$-7.40E \times 10^{-2}$	-3.00E	$6.70E \times 10^{-2}$
5.00E	$3.10E \times 10^{-2}$	3.45E	$-7.70E \times 10^{-2}$	-2.45E	$6.50E \times 10^{-2}$
6.00E	$3.04E \times 10^{-2}$	3.10E	$-8.00E \times 10^{-2}$	-2.10E	$5.90E \times 10^{-2}$
7.00E	$3.00E \times 10^{-2}$	2.80E	$-8.40E \times 10^{-2}$	-1.80E	$4.75E \times 10^{-2}$
8.00E	$2.95E \times 10^{-2}$	2.50E	$-8.75E \times 10^{-2}$	-1.50E	$3.50E \times 10^{-2}$
9.00E	$2.95E \times 10^{-2}$	2.25E	$-9.10E \times 10^{-2}$	-1.25E	$2.25E \times 10^{-2}$
1.00E × 10	2.94E × 10 ⁻²	2.00E	$-9.50E \times 10^{-2}$	-1.00E	$10.00E \times 10^{-3}$

TABLE 7
THICK-TARGET BREMSSTRAHLUNG PRODUCTION IN ALUMINUM

	(a) $T_0 = 0.5 \text{ MeV}$			(b) $T_{O} = 1.0 \text{ MeV}$			
k, MeV	Theoretical $\frac{k \ d\sigma}{dk \ d\Omega}$, $\frac{MeV}{MeV-sr-electron}$ (eq. (19))	Experimental $\frac{k d\sigma}{dk d\Omega}$, MeV MeV-sr-electron (ref. 15)	k, MeV	Theoretical $\frac{k d\sigma}{dk d\Omega}$, MeV MeV-sr-electron (eq. (19))	Experimental $\frac{k d\sigma}{dk d\Omega}$, MeV MeV-sr-electron (ref. 15)		
	$\phi_{\mathbf{d}} = 0^{0}$	I	'	$\phi_d = 0^{\circ}$			
0.05	1.947×10^{-3}	1.450×10^{-3}	0.10	6.010 × 10 ⁻³	4.986×10^{-3}		
.10	1.426×10^{-3}	1.297×10^{-3}	.20	4.367×10^{-3}	3.973×10^{-3}		
.15	1.087×10^{-3}	1.001×10^{-3}	.30	3.189×10^{-3}	3.280×10^{-3}		
.20	8.155×10^{-4}	7.765×10^{-4}	.40	2.255×10^{-3}	2.770×10^{-3}		
.25	5.915×10^{-4}	6.348×10^{-4}	.50	1.547×10^{-3}	2.286×10^{-3}		
.30	4.029×10^{-4}	4.747×10^{-4}	.70	5.773×10^{-4}	1.240×10^{-3}		
.35	2.474×10^{-4}	3.160×10^{-4}	.90	1.121×10^{-4}	3.744×10^{-4}		
.40	1.257×10^{-4}	2.286×10^{-4}	1	1	3.		
.45	4.046×10^{-5}	1.056×10^{-4}		$\phi_{d} = 15^{O}$			
1	$\phi_{\mathbf{d}} = 15^{0}$		0.10	5.772×10^{-3}	3.595×10^{-3}		
			.20	4.154×10^{-3}	2.861×10^{-3}		
0.05	1.831×10^{-3}	1.502×10^{-3}	.30	3.001×10^{-3}	2.373×10^{-3}		
.10	1.337×10^{-3}	1.437×10^{-3}	.40	2.086×10^{-3}	2.039×10^{-3}		
.15	1.009×10^{-3}	1.080×10^{-3}	.50	1.408 × 10 ⁻³	1.686×10^{-3}		
.20	7.579×10^{-4}	8.409×10^{-4}	.70	5.096×10^{-4}	9.395×10^{-4}		
.25	5.464×10^{-4}	6.553×10^{-4}	.90	9.412×10^{-5}	4.000×10^{-4}		
.30	3.700×10^{-4}	5.228×10^{-4}	ļ <u> </u>	Ī			
.35	2.258×10^{-4}	3.816×10^{-4}		$\phi_{\mathbf{d}} = 20^{\circ}$			
.40	1.141×10^{-4}	2.635×10^{-4}	l 		_		
.45	3.659×10^{-5}	1.509×10^{-4}	0.10	5.291×10^{-3}	3.692×10^{-3}		
			.20	3.851×10^{-3}	2.756×10^{-3}		
	$\phi_{\mathbf{d}} = 30^{0}$.30	2.772×10^{-3}	2.304×10^{-3}		
			.40	1.911×10^{-3}	1.920×10^{-3}		
0.05	1.482×10^{-3}	1.232×10^{-3}	.50	1.282×10^{-3}	1.499×10^{-3}		
.10	1.081×10^{-3}	1.140×10^{-3}	.70	4.592×10^{-4}	7.970×10^{-4}		
.15	8.125×10^{-4}	8.410×10^{-4}	.90	8.426×10^{-5}	2.444×10^{-4}		
.20	6.064×10^{-4}	6.453×10^{-4}	·				
.25	4.336×10^{-4}	5.130×10^{-4}		$\phi_{\mathbf{d}} = 30^{\circ}$			
.30	2.913×10^{-4}	3.918×10^{-4}		3	3		
.35	$1.768 \times 10^{-4} \\ 8.924 \times 10^{-5}$	2.893×10^{-4}	0.10	4.317×10^{-3} 3.076×10^{-3}	2.502×10^{-3}		
.40	8.924×10^{-5} 2.884×10^{-5}	$1.969 \times 10^{-4} \\ 1.170 \times 10^{-4}$.20	3.076×10^{-3}	1.899×10^{-3}		
.45	2.884 × 10	1.170 × 10 -	.30	1.478×10^{-3}	1.536×10^{-3} 1.219×10^{-3}		
		1	.40	9.719×10^{-4}	9.329×10^{-4}		
	$\phi_{\mathbf{d}} = 60^{\mathbf{o}}$	}	.70	3.377×10^{-4}	4.650×10^{-4}		
0.05	7.347×10^{-4}	7.691×10^{-4}	.90	6.150×10^{-5}	1.500×10^{-4}		
.10	7.347×10 5.252×10^{-4}	6.979×10^{-4}	.50	0.150 ^ 10	1.300 × 10		
.15	3.823×10^{-4}	4.866×10^{-4}		$\phi_{ m d}$ = 60°			
.20	2.749×10^{-4}	3.543×10^{-4}		Ψd = 50			
.25	1.880×10^{-4}	2.642×10^{-4}	0.10	1.850×10^{-3}	1.339×10^{-3}		
.30	1.211 × 10 ⁻⁴	1.914 × 10 ⁻⁴	.20	1.239×10^{-3}	9.464×10^{-4}		
.35	7.083×10^{-9}	1.315 × 10 ⁻⁴	.30	8.028×10^{-4}	6.804×10^{-4}		
I	3.481×10^{-5}	8.318 × 10 ⁻⁵	.40	4.829×10^{-4}	5.296×10^{-4}		
	0.104 - 1 10	0,010 10	1 1	4	0.250 A 10		
.40 45	1.122×10^{-5}	3.964×10^{-5}	.50	2.806 × 10 ^	3.668 × 10 -		
.45	1.122 × 10 ⁻⁵	3.964 × 10 ⁻⁵	.50 .70	2.806×10^{-4} 8.070×10^{-5} 1.358×10^{-5}	3.668×10^{-4} 1.410×10^{-4} 2.950×10^{-5}		

TABLE 8
THICK-TARGET BREMSSTRAHLUNG PRODUCTION IN IRON

	(a) $T_0 = 0.5 M$	1eV		(b) T _o = 1.0 MeV				
k, MeV	Theoretical $\frac{k d\sigma}{dk d\Omega}$, MeV MeV-sr-electron (eq. (19))	Experimental $\frac{k d\sigma}{dk d\Omega}$, MeV MeV-sr-electron (ref. 15)	k, MeV	Theoretical $\frac{k d\sigma}{dk d\Omega}$, MeV MeV-sr-electron (eq. (19))	Experimental $\frac{k d\sigma}{dk d\Omega}$, MeV MeV-sr-electron (ref. 15)			
	$\phi_{\mathbf{d}} = 0^{\mathbf{O}}$			$\phi_{\mathbf{d}} = 0^{0}$				
¦ ,	1			ı				
0.05	3.705×10^{-3}	1.282×10^{-3}	0.10	1.052×10^{-2}	7.318×10^{-3}			
.10	2.676×10^{-3}	2.190×10^{-3}	.20	7.592×10^{-3}	6.193×10^{-3}			
.15	1.997×10^{-3}	1.863×10^{-3}	.30	5.651×10^{-3}	5.265×10^{-3}			
.20	1.478×10^{-3}	1.507×10^{-3}	.40	4.158×10^{-3}	4.520×10^{-3}			
.25	1.056×10^{-3}	1.249×10^{-3}	.50	2.949×10^{-3}	3.769×10^{-3}			
.30	7.101×10^{-4}	1.028×10^{-3}	.70	1.178×10^{-3}	2.179×10^{-3}			
.35	4.302×10^{-4}	7.830×10^{-4}	.90	1.867×10^{-4}	8.892×10^{-4}			
.40	2.167×10^{-4}	6.088×10^{-4}	Ì		'			
.45	6.976 × 10 ⁻⁵	4.296 × 10 ⁻⁴		$\phi_{\rm d} = 20^{\rm O}$				
1	$\phi_{\mathbf{d}} = 15^{\mathrm{O}}$. –	0.10	1.004×10^{-2}	5.349×10^{-3}			
l .	$\varphi_{\mathbf{d}} = 13$.20	7.195×10^{-3}	4.420×10^{-3}			
0,05	3.619×10^{-3}	4.261×10^{-4}	.30	5.296×10^{-3}	3.659×10^{-3}			
.10	2.606×10^{-3}	1.893 × 10 ⁻³	.40	3.845×10^{-3}	2.941×10^{-3}			
.15	1.936×10^{-3}	1.592×10^{-3}	.50	2.681×10^{-3}	2.453×10^{-3}			
.20	1.426×10^{-3}	1.352×10 1.269×10^{-3}	.70	1.028×10^{-3}	1.408×10^{-3}			
.25	1.014×10^{-3}	1.040×10^{-3}	.90	1.562×10^{-4}	5.838 × 10 ⁻⁴			
.30	6.771×10^{-4}	8.323 × 10 ⁻⁴	.50	1.302 × 10	3.000 × 10			
.35	4.077×10^{-4}	6.494 × 10 ⁻⁴		$\phi_{\mathbf{d}} = 30^{0}$				
.40	2.039×10^{-4}	4.698 × 10 ⁻⁴	ļ	φd - 30	,			
.45	6.526×10^{-5}	3.159×10^{-4}	0.10	8.830×10^{-3}	4.433×10^{-3}			
			.20	6.296×10^{-3}	3.589×10^{-3}			
ĺ	$\phi_{\rm d} = 30^{\rm O}$.30	4.600×10^{-3}	2.943×10^{-3}			
!	1	,	.40	3.308×10^{-3}	2.426×10^{-3}			
0.05	3.281×10^{-3}	8.680 × 10 ⁻⁴	.50	2.277×10^{-3}	1.968×10^{-3}			
.10	2.353×10^{-3}	1.557×10^{-3}	.70	8.508×10^{-4}	1.217×10^{-3}			
.15	1.737×10^{-3}	1.320×10^{-3}	.90	1.278×10^{-4}	3.686 × 10 ⁻⁴			
.20	1.269×10^{-3}	1.052×10^{-3}	1	1				
.25	8.953×10^{-4}	8.577×10^{-4}						
.30	5.925×10^{-4}	6.717×10^{-4}						
.35	3.534×10^{-4}	5.242×10^{-4}						
.40	1.755×10^{-4}	3.698×10^{-4}						
.45	5.595 × 10 ⁻⁵	2.423 × 10 ⁻⁴						
ĺ	0	'						
	$\phi_{\mathbf{d}} = 60^{\circ}$							
0.05	2.279×10^{-3}	6.997 × 10 ⁻⁴						
.10	1.601×10^{-3}	9.952×10^{-4}						
.15	1.143 × 10 ⁻³	9.952×10^{-4} 8.660×10^{-4}						
.20	8.010×10^{-4}	6.781 × 10 ⁻⁴						
.25	5.448 × 10 ⁻⁴	5.259×10^{-4}						
.30	3.475×10^{-4}	4,008 × 10 ⁻⁴						
.35	2,001 × 10 ⁻⁴	2.820×10^{-4}						
.40	9.646×10^{-5}	1.895×10^{-4}						
.45	3.036 × 10 ⁻⁵	1.044 × 10 ⁻⁴						
	1							

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